

CE

CHENYI ELECTRONICS

SRF1020 THRU SRF1620(SINGLE CHIP)**SCHOTTKY BARRIER RECTIFIER****Reverse Voltage - 20 to 60 Volts****Forward Current - 10.0 Amperes****FEATURES**

- . Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- . Metal silicon junction ,majority carrier conduction
- . Guard ring for overvoltage protection
- . Low power loss,high efficiency
- . High current capability ,Low forward voltage drop
- . Single rectifier construction
- . High surge capability
- . For use in low voltage ,high frequency inverters,
free wheeling , and polarity protection applications
- . High temperature soldering guaranteed: 250°C/10 seconds
0.25"(6.35mm)from case

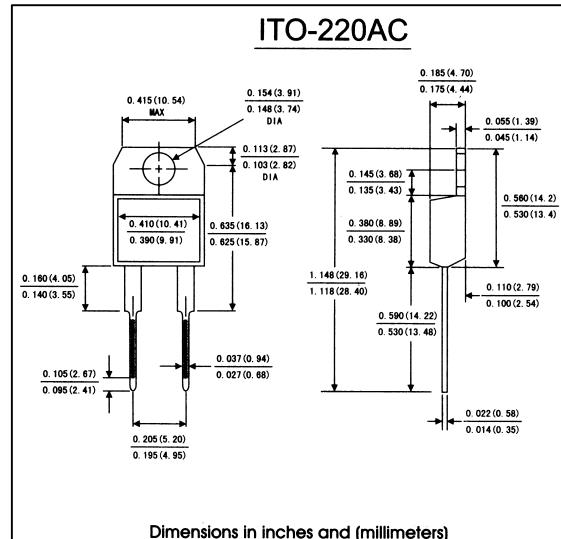
MECHANICAL DATA

- . **Case:** JEDEC DO-220AC molded plastic body
- . **Terminals:** lead solderable per MIL-STD-750,method 2026
- . **Polarity:** As marked
- . **Mounting Position:** Any
- . **Weight:** 0.08 ounce, 1.81 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified,Single phase,half wave,resistive or inductive)

load. For capacitive load,derate by 20%)



Dimensions in inches and (millimeters)

	Symbols	SRF1020	SRF1030	SRF1040	SRF1050	SRF1060	Units			
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	Volts			
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	Volts			
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	Volts			
Macimum average forward rectified current(see Fig.1)	I _(AV)	10.0					Amps			
Repetitive peak forward current(square wavr, 20KHz) at T _c =105°C	I _{FRM}	20.0					Amps			
Peak forward surge current 8.3ms singel half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0					Amps			
Maximum instantaneous forward voltage at 10 A(Note 1)	V _F	0.70		0.80		Volts				
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	TA=25°C TA=125°C	I _R	1.0			mA				
Typeical thermal resistance(Note 2)			30							
Operating junction temperature range	T _J	-65 to +150					°C			
storage temperature range	T _{STG}	-65 to +150					°C			

Notes: 1. Pulse test: 300 μ s pulse width,1% duty cycle

2.Thermal resistance from juntion to case

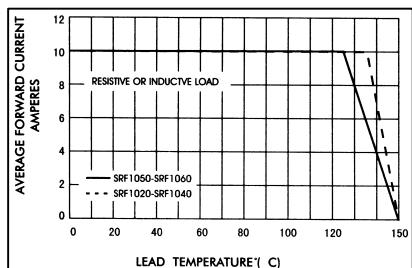
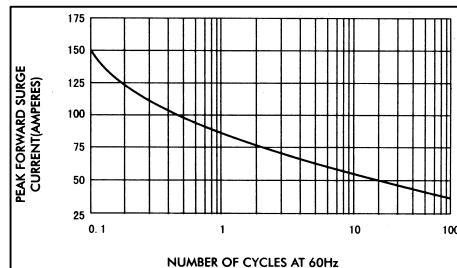
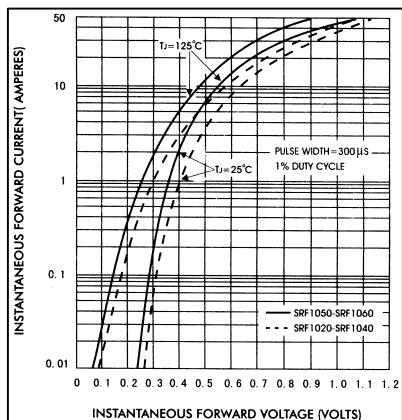
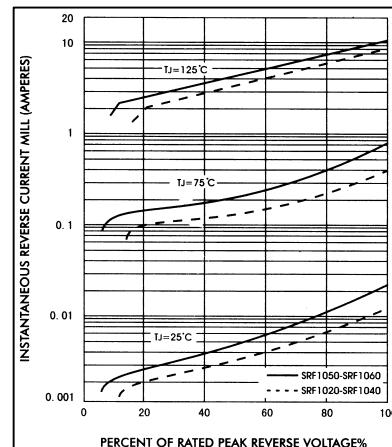
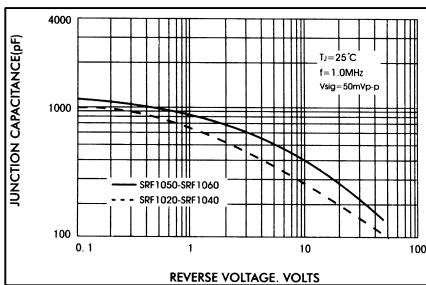
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RATINGS AND CHARACTERISTIC CURVES SRF1020 THRU SRF1620**FIG.1-FORWARD CURRENT DERATING CURVE****FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT****FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS****FIG.4-TYPICAL REVERSE CHARACTERISTICS****FIG.5-TYPICAL JUNCTION CAPACITANCE****FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE**